Diode Semiconductor Device - Page 1 of 1



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## Inclosure Material:

Glass

# Overall Length:

Between 0.130 inches and 0.300 inches

# **Terminal Length:**

Between 0.900 inches and 1.300 inches

## **Overall Diameter:**

Between 0.115 inches and 0.180 inches

### Mounting Method:

Terminal

#### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

460.0 breakdown voltage, dc and 400.0 working peak reverse voltage

## **Current Rating Per Characteristic:**

5.00 amperes forward current, average absolute

# Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

# Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0